

Features:

- 10 Mhz bandwidth typical
- 40kVdc isolation test voltage
- TTL compatible input and output
- High common mode rejection
- Rugged ceramic package

Applications:

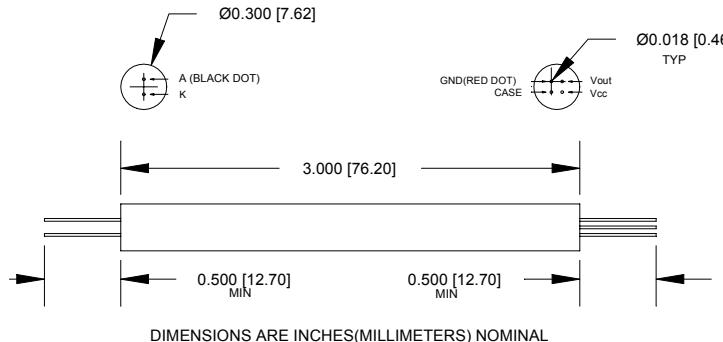
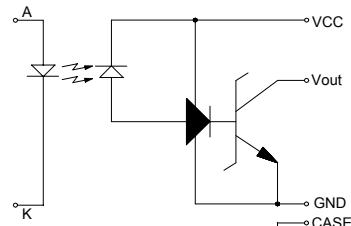
- Military and Space
- Voltage Level Shifting
- Grid Current Modulator
- Switching between power supplies
- Medical systems

DESCRIPTION

The **66147** high voltage isolation consisting of a LED optically coupled to a high speed, high gain inverting detector gate. Output is TTL capable with switching propagation delays of 55ns typical, hermetically sealed in TO-46 packages and mounted in a highly reliability, hermetically sealed ceramic package. Available in commercial (0° to +70°C), extended temperature range (-40° to +85°) and full Military temperature range (-55° to +125°C). **Contact the factory for special custom or multi-channel requirements!**

ABSOLUTE MAXIMUM RATINGS

Storage Temperature.....	-65°C to +150°C
Operating Free-Air Temperature Range	-55°C to +125°C
Lead Solder Temperature.....	260°C for 10s (1.6mm below seating plane)
Peak Forward Input Current	40mA (1ms duration)
Average Forward Input Current	20mA
Input Power Dissipation	35mW
Reverse Input Voltage	5V
Supply voltage - V _{CC}	7V(1 minute maximum)
Output Current - I _O	25mA
Output Power Dissipation	40mW
Output Voltage - V _O	7V
Total Power Dissipation	350mW

Package Dimensions**Schematic Diagram**

ELECTRICAL CHARACTERISTICS $T_a = 25^\circ\text{C}$ unless otherwise specified.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
High Level Output Current	I_{OH}		5	250	μA	$V_{CC} = 5.5\text{V}, V_O = 5.5\text{V}, I_F = 20\mu\text{A}$	
Low Level Output Voltage	V_{OL}		0.35	0.6	V	$V_{CC} = 5.5\text{V}, I_F = 10\text{mA}$ I_{OL} (Sinking) = 10mA	
High Level Supply Current	I_{CCH}		9	20	mA	$V_{CC} = 5.5\text{V}, I_F = 0$	
Low Level Supply Current	I_{CCL}		13	30	mA	$V_{CC} = 5.5\text{V}, I_F = 20\text{mA}$	
Input Forward Voltage	V_F		1.5	1.75	V	$I_F = 15\text{mA}$	
Input Reverse Breakdown Voltage	BV_R	5			V	$I_R = 10\mu\text{A}$	
Input-Output Insulation Leakage Current	I_{I-O}			10	μA	$V_{CC} = 40\text{kVdc},$ Relative Humidity = 45% $T_a = 25^\circ\text{C}, t = 5 \text{ sec}$	
Propagation Delay Time To High Output Level	t_{PLH}		45	95	ns	$R_L = 510\Omega, C_L = 15\text{pf},$ $I_f = 13\text{mA}$	
Propagation Delay Time To Low Output Level	t_{PHL}		55	110	ns	$R_L = 510\Omega, C_L = 15\text{pf}$ $I_f = 13\text{mA}$	

TYPICAL CHARACTERISTICS $T_a = 25^\circ\text{C}, V_{CC} = 5\text{V}$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS	NOTE
Input Diode Temperature Coefficient	$\frac{\Delta V_F}{\Delta T_A}$		-1.9		mV/ $^\circ\text{C}$	$I_F = 20\text{mA}$	1
Resistance (Input-Output)	R_{I-O}		10^{12}		Ω	$V_{I-O} = 500\text{V}$	3
Input-Input Insulation Leakage Current	I_{I-I}		0.5		nA	Relative Humidity = 45% $V_{I-I} = 500\text{V}, t = 5\text{s}$	4
Resistance (Input-Input)	R_{I-I}		10^{12}		Ω	$V_{I-I} = 500\text{V}$	4
Common Mode Transient Immunity at High Output Level	CM_H	1000	10000		V/ μs	$V_{CM} = 10\text{V}$ (peak), V_O (min) = 2V, $R_L = 510\Omega, I_F = 0\text{mA}$	7
Common Mode Transient Immunity at Low Output Level	CM_L	1000	10000		V/ μs	$V_{CM} = 10\text{V}$ (peak), V_O (max) = 0.8V, $R_L = 510\Omega, I_F = 10\text{mA}$	8

NOTES:

- Each channel
- Measured between pins 1 through 8 shorted together and pins 9 through 16 shorted together.
- Measured between pins 9 and 10 or 11 and 12 shorted together, and pins 9 through 16 shorted together.
- Measured between pins 9 and 10 shorted together, and pins 11 and 12 shorted together.
- The t_{plh} propagation delay is measured from the 6.5mA point on the trailing edge of the input pulse to the 1.5V point on the trailing edge of the output pulse.
- The t_{phl} propagation delay is measured from the 6.5mA point on the leading edge of the input pulse to the 1.5V point on the leading edge of the output pulse.
- CM_H is the max. tolerable common mode transient to assure that the output will remain in a high logic state (i.e. $V_O > 2.0\text{V}$).
- CM_L is the max. tolerable common mode transient to assure that the output will remain in a low logic state (i.e. $V_O < 0.8\text{V}$).
- It is essential that a bypass capacitor (.01 to 0.1 μF ceramic) be connected from pin 1 to pin 4.

RECOMMENDED OPERATING CONDITIONS:

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Current, Low Level Each Channel	I_{FL}	0	250	μA
Input Current, High Level Each Channel	I_{FH}	12.5	20	mA
Supply Voltage	V_C	4.5	5.5	V
Fan Out (TTL Load) Each Channel	N		6	
Operating Temperature	T_A	-55	125	$^\circ\text{C}$

SELECTION GUIDE

PART #	PART DESCRIPTION
66147-001	Inverted output, military operating range (-55° to +125° $^\circ\text{C}$)
66147-102	Inverted output, full mil-temp (-55° to +125° $^\circ\text{C}$) with 100% device screening (on discrete components)
66147-011	Inverted output, commercial version Isolator(0° to 70° $^\circ\text{C}$)